# PHOTOCOUPLER PS2601,PS2602,PS2601L,PS2602L

# HIGH ISOLATION VOLTAGE 6-PIN PHOTOCOUPLER

-NEPOC<sup>™</sup> Series-

#### DESCRIPTION

NEC

The PS2601, PS2602, PS2601L, PS2602L are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor in a plastic DIP (Dual In-line Package).

The PS2601L, PS2602L are lead bending type (Gull-wing) for surface mount.

#### FEATURES

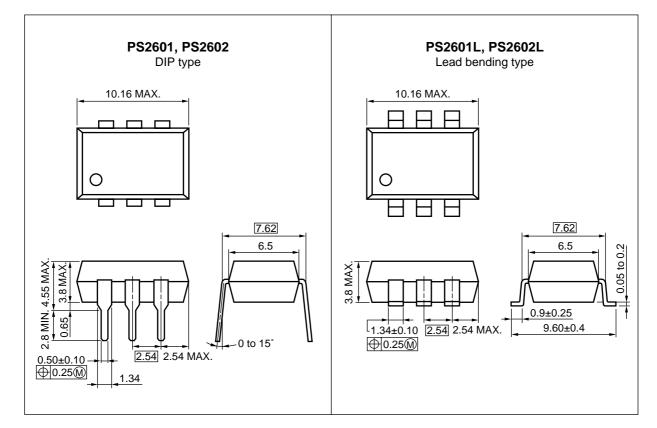
- High Isolation voltage (BV = 5 000 Vr.m.s.)
- High collector to emitter voltage (VCEO = 80 V)
- High-speed switching (tr = 3  $\mu$ s TYP., tr = 5  $\mu$ s TYP.)
- High current transfer ratio (CTR = 300 % TYP.)
- UL approved: File No. E72422 (S)
- Ordering number of taping product: PS2601L-E3, E4, PS2602L-E3, E4

#### **★** APPLICATIONS

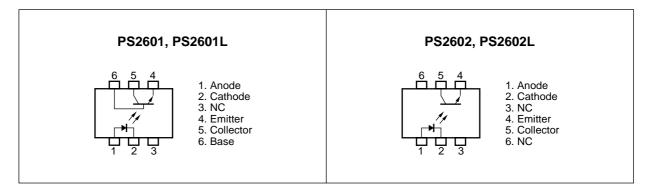
- Power supply, SSR
- Telephone, FAX
- AC/DC line interface
- Electric home appliances

The information in this document is subject to change without notice.

\* PACKAGE DIMENSIONS (in millimeters)



## PIN CONNECTIONS (TOP VIEW)



| Parameter                       |                                    | Symbol              | Ratings     | Unit    |
|---------------------------------|------------------------------------|---------------------|-------------|---------|
| Diode                           | Forward Current (DC)               | ١F                  | 80          | mA      |
|                                 | Reverse Voltage                    | VR                  | 6.0         | V       |
|                                 | Power Dissipation Derating         | ⊿P <sub>D</sub> /°C | 1.5         | mW/°C   |
|                                 | Power Dissipation                  | PD                  | 150         | mW      |
|                                 | Peak Forward Current <sup>*1</sup> | IFP                 | 1           | А       |
| Transistor                      | Collector to Emitter Voltage       | Vceo                | 80          | V       |
|                                 | Emitter to Collector Voltage       | Veco                | 7           | V       |
|                                 | Collector Current                  | Ic                  | 50          | mA      |
|                                 | Power Dissipation Derating         | ⊿Pc/°C              | 1.5         | mW/°C   |
|                                 | Power Dissipation                  | Pc                  | 150         | mW      |
| Isolation Voltage <sup>'2</sup> |                                    | BV                  | 5 000       | Vr.m.s. |
| Operating Ambient Temperature   |                                    | TA                  | –55 to +100 | °C      |
| Storage Temperature             |                                    | Tstg                | –55 to +150 | °C      |

# ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

\*1 PW = 100  $\mu$ s, Duty Cycle = 1 %

\*2 AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input and output

| Parameter  |   | Symbol    | Conditions  | MIN.             | TYP. | MAX. | Unit |
|------------|---|-----------|---|------------------|------|------|------|
| Diode      | Forward Voltage                                 | VF        | IF = 10 mA  |                  | 1.1  | 1.4  | V    |
|            | Reverse Current                                 | lr        | V <sub>R</sub> = 5 V                                  |                  |      | 5.0  | μA   |
|            | Terminal Capacitance                            | Ct        | V = 0 V, f = 1.0 MHz                                  |                  | 30   |      | pF   |
| Transistor | Collector to Emitter<br>Dark Current            | ICEO      | $V_{CE} = 80 \text{ V}, \text{ I}_{F} = 0 \text{ mA}$ |                  |      | 100  | nA   |
|            | DC Current Gain <sup>*1</sup>                   | hfe       | Ic = 2 mA, Vce = 5 V                                  |                  | 700  |      |      |
| Coupled    | Current Transfer Ratio<br>(Ic/IF) <sup>*2</sup> | CTR       | IF = 5 mA, Vce = 5 V                                  | 80               | 300  | 600  | %    |
|            | Collector Saturation<br>Voltage                 | VCE (sat) | IF = 10 mA, Ic = 2 mA                                 |                  |      | 0.3  | V    |
|            | Isolation Resistance                            | Ri-o      | VI-O = 1.0 kVDC                                       | 10 <sup>11</sup> |      |      | Ω    |
|            | Isolation Capacitance                           | CI-O      | V = 0 V, f = 1.0 MHz                                  |                  | 0.6  |      | pF   |
|            | Rise Time <sup>'3</sup>                         | tr        | $V_{CC}$ = 5 V, Ic = 2 mA, RL = 100 $\Omega$          |                  | 3    |      | μs   |
|            | Fall Time <sup>*</sup>                          | tr        |   |                  | 5    |      |      |

## ELECTRICAL CHARACTERISTICS (TA = 25 °C)

\*1 PS2601, PS2601L only

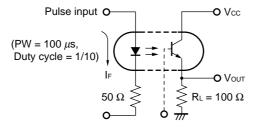
\*2 CTR rank

K: 300 to 600 (%)

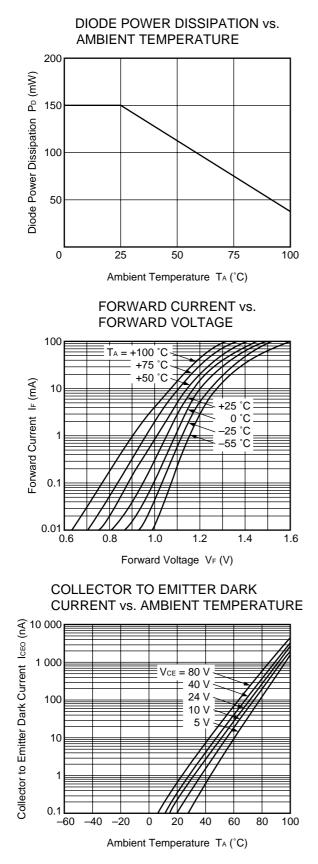
L: 200 to 400 (%)

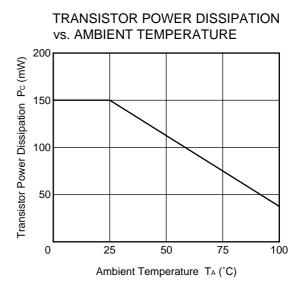
M: 80 to 240 (%)

\*3 Test circuit for switching time

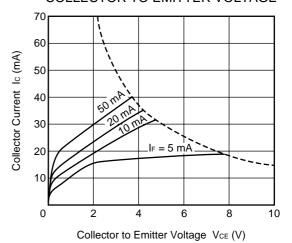


#### \* TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

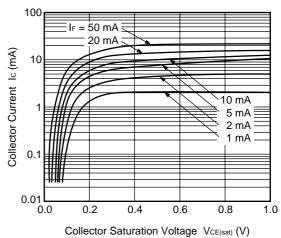




COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



CURRENT TRANSFER RATIO vs.

FORWARD CURRENT

400

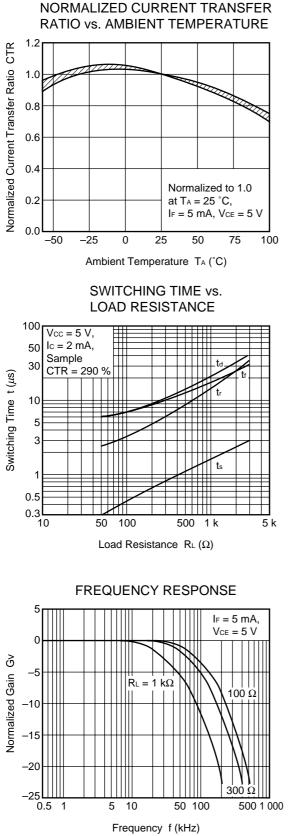
300

200

100

10

50



Current Transfer Ratio CTR (%) С 0 0.05 0.1 0.5 0.5 5 1 Forward Current IF (mA) SWITCHING TIME vs. LOAD RESISTANCE 1 000

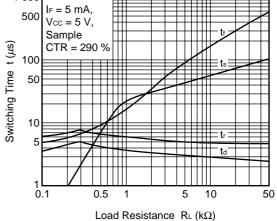
Vce = 5 V

200

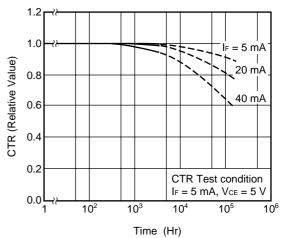
150

100

50



LONG TERM CTR DEGRADATION



Remark The graphs indicate nominal characteristics.

## **RECOMMENDED SOLDERING CONDITIONS**

### (1) Infrared reflow soldering

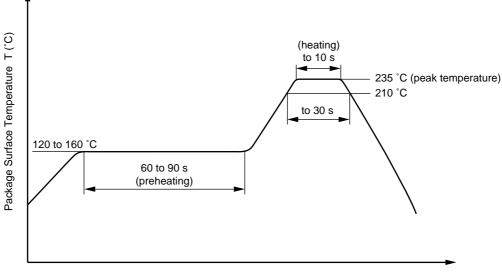
- Peak reflow temperature
  235 °C (package surface temperature)
- Time of temperature higher than 210 °C
- Number of reflows
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

#### Recommended Temperature Profile of Infrared Reflow

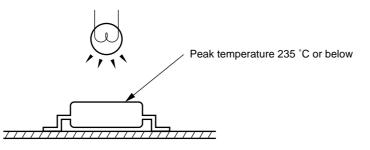
30 seconds or less

Three





#### Caution Please avoid removing the residual flux by water after the first reflow process.



#### (2) Dip soldering

- Temperature 260 °C or below (molten solder temperature)
- Time
  - ne 10 seconds or less mber of times One
- Number of times
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

# CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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Anti-radioactive design is not implemented in this product.

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